

Octal D Flip-Flop with 3-State Outputs

MC74AC574, MC74ACT574

The MC74AC574/74ACT574 is a high-speed, low power octal flip-flop with a buffered common Clock (CP) and a buffered common Output Enable (\overline{OE}) . The information presented to the D inputs is stored in the flip-flops on the LOW-to-HIGH Clock (CP) transition.

The MC74AC574/74ACT574 is functionally identical to the MC74AC374/74ACT374 except for the pinouts.

Features

- Inputs and Outputs on Opposite Sides of Package Allowing Easy Interface with Microprocessors
- Useful as Input or Output Port for Microprocessors
- Functionally Identical to MC74AC374/74ACT374
- 3-State Outputs for Bus-Oriented Applications
- Outputs Source/Sink 24 mA
- 'ACT574 Has TTL Compatible Inputs
- Pb-Free Packages are Available

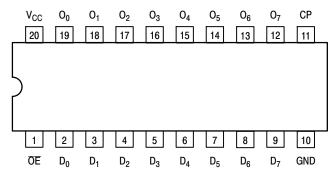


Figure 1. Pinout: 20-Lead Packages Conductors

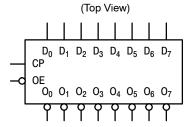


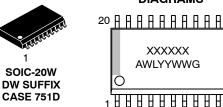
Figure 2. Logic Symbol

PIN ASSIGNMENT

Pin	Function
D ₀ -D ₇	Data Inputs
СР	Clock Pulse Input
ŌE	3-State Output Enable Input
O ₀ -O ₇	3-State Outputs

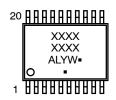
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MARKING DIAGRAMS





TSSOP-20 DT SUFFIX CASE 948E



XXXXXX = Specific Device Code

A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week

G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.

FUNCTIONAL DESCRIPTION

The MC74AC574/74ACT574 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-state true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable (\overline{OE}) LOW, the contents of the eight flip-flops are available at the outputs. When \overline{OE} is HIGH, the outputs go to the high impedance state. Operation of the \overline{OE} input does not affect the state of the flip-flops.

FUNCTION TABLE

	Inputs		Internal	Outputs	
OE	CP	D	Q	O _n	Function
Н	Н	L	NC	Z	Hold
Н	Н	Н	NC	Z	Hold
Н	工	L	L	Z	Load
Н	_	Н	Н	Z	Load
L	_	L	L	L	Data Available
L	_	Н	Н	Н	Data Available
L	Н	L	NC	NC	No Change in Data
L	Н	Н	NC	NC	No Change in Data

H = HIGH Voltage Level

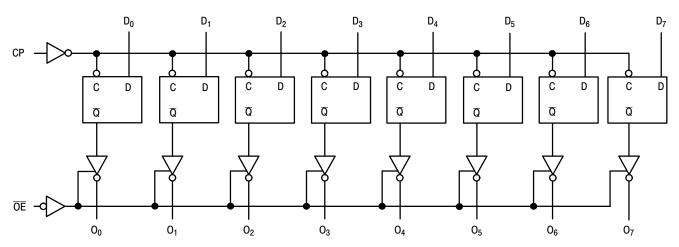
L = LOW Voltage Level

X = Immaterial

Z = High Impedance

= LOW-to-HIGH Clock Transition

NC = No Change



NOTE: This diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Figure 3. Logic Diagram

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +6.5	V
V _{IN}	DC Input Voltage (Referenced to GND)	-0.5 to V _{CC} +0.5	V
V _{OUT}	DC Output Voltage (Referenced to GND)	-0.5 to V _{CC} +0.5	V
I _{IN}	DC Input Current, per Pin	±20	mA
l _{out}	DC Output Sink/Source Current, per Pin	±50	mA
I _{CC}	DC V _{CC} or GND Current per Output Pin	±50	mA
T _{stg}	Storage Temperature	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Тур	Max	Unit
V _{CC}	Supply Voltage	'AC	2.0	5.0	6.0	V
		'ACT	4.5	5.0	5.5	
V _{IN} , V _{OUT}	DC Input Voltage, Output Voltage (Ref. to GND)		0	_	V _{CC}	V
t _r , t _f	Input Rise and Fall Time (Note 1)	V _{CC} @ 3.0 V	-	150	_	
	'AC Devices except Schmitt Inputs	V _{CC} @ 4.5 V	-	40	_	ns/V
		V _{CC} @ 5.5 V	-	25	-	
t _r , t _f	Input Rise and Fall Time (Note 2)	V _{CC} @ 4.5 V	-	10	_	ns/V
	'ACT Devices except Schmitt Inputs	V _{CC} @ 5.5 V	-	8.0	_	
T _A	Operating Ambient Temperature Range		-40	25	85	°C
I _{OH}	Output Current – High		-	_	-24	mA
l _{OL}	Output Current – Low		_	_	24	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. V_{IN} from 30% to 70% V_{CC}; see individual Data Sheets for devices that differ from the typical input rise and fall times.

2. V_{IN} from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

DC CHARACTERISTICS

			74	C	74AC			
		V _{CC}	T _A = +	25 °C	T _A = -40 °C to +85 °C	1		
Symbol	Parameter	(V)	Тур	(Guaranteed Limits	Unit	Conditions	
V _{IH}	Minimum High Level Input Voltage	3.0	1.5	2.1	2.1	V	V _{OUT} = 0.1 V	
		4.5	2.25	3.15	3.15		or V _{CC} – 0.1 V	
		5.5	2.75	3.85	3.85			
V _{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.9	0.9	V	V _{OUT} = 0.1 V	
		4.5	2.25	1.35	1.35		or V _{CC} – 0.1 V	
		5.5	2.75	1.65	1.65			
V _{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	٧	I _{OUT} = -50 μA	
		4.5	4.49	4.4	4.4			
		5.5	5.49	5.4	5.4			
						٧	*V _{IN} = V _{IL} or V _{IH}	
		3.0	-	2.56	2.46		-12 mA	
		4.5	-	3.86	3.76		I _{OH} –24 mA	
		5.5	-	4.86	4.76		−24 mA	
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	٧	I _{OUT} = 50 μA	
		4.5	0.001	0.1	0.1			
		5.5	0.001	0.1	0.1			
						V	$*V_{IN} = V_{IL} \text{ or } V_{IH}$	
		3.0	-	0.36	0.44		12 mA	
		4.5	-	0.36	0.44		I _{OL} 24 mA	
		5.5	-	0.36	0.44		24 mA	
I _{IN}	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μΑ	$V_I = V_{CC}$, GND	
l _{OLD}	†Minimum Dynamic Output Current	5.5	_	_	75	mA	V _{OLD} = 1.65 V Max	
I _{OHD}		5.5	-	_	-75	mA	V _{OHD} = 3.85 V Min	
I _{CC}	Maximum Quiescent Supply Current	5.5	_	8.0	80	μΑ	V _{IN} = V _{CC} or GND	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. NOTE: Note: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC} .

^{*} All outputs loaded; thresholds on input associated with output under test.
† Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS (For Figures and Waveforms – See AND8277/D at www.onsemi.com)

				74AC		74.	AC		
		V _{CC} *	7	T _A = +25 °(C _L = 50 pF	= +25 °C			Fig.	
Symbol	Parameter	(V)	Min	Тур	Max	Min	Max	Unit	No.
f _{max}	Maximum Clock Frequency	3.3	75	-	-	60	-	MHz	3–3
		5.0	95	-	-	85	-		
t _{PLH}	Propagation Delay	3.3	3.5	-	13.5	3.5	15	ns	3–6
	CP to O _n		2.0	-	9.5	2.0	11	1	
t _{PHL}	Propagation Delay	3.3	3.5	-	12	3.5	13.5	ns	3–6
	CP to O _n	5.0	2.0	-	8.5	2.0	9.5		
t _{PZH}	Output Enable Time	3.3	2.5	-	11	2.5	12	ns	3–7
		5.0	2.0	-	8.5	2.0	9.0		
t _{PZL}	Output Enable Time	3.3	3.0	-	10.5	3.5	11.5	ns	3–8
		5.0	1.5	-	8.0	2.0	9.0		
t _{PHZ}	Output Disable Time	3.3	4.0	_	12	4.0	13	ns	3–7
		5.0	2.0	-	9.5	2.0	10.5		
t _{PLZ}	Output Disable Time	3.3	2.0	-	9.0	2.5	10	ns	3–8
		5.0	1.5	-	7.5	1.5	8.5		

Voltage Range 3.3 V is 3.3 V ± 0.3 V. Voltage Range 5.0 V is 5.0 V ± 0.5 V.

AC OPERATING REQUIREMENTS

			74AC		74AC		
		Voo*	T _A = + C _L = 5	-25 °C 50 pF	T _A = -40 °C to +85 °C C _L = 50 pF		Fig.
Symbol	Parameter	V _{CC} * (V)	Тур	Gu	aranteed Minimum	Unit	No.
t _s	Setup Time, HIGH or LOW	3.3	-	2.5	3.0	ns	3–9
	D _n to CP	5.0	-	1.5	2.0		
t _h	Hold Time, HIGH or LOW	3.3	-	1.5	1.5	ns	3–9
	D _n to CP	5.0	-	1.5	1.5		
t _w	CP Pulse Width HIGH or LOW	3.3	-	6.0	7.0	ns	3–6
		5.0	-	4.0	5.0		

Voltage Range 3.3 V is 3.3 V ±0.3 V.
 Voltage Range 5.0 V is 5.0 V ±0.5 V.

DC CHARACTERISTICS

			74ACT 74ACT								
		V _{CC}	T _A = +	.25 °C	T _A = -40 °C to +85 °C						
Symbol	Parameter	(V)	Тур	G	uaranteed Limits	Unit	(Conditions			
V_{IH}	Minimum High Level Input Voltage	4.5	1.5 2.0		5 1.5 2.0		2.0	V	V _{OUT} = 0.1 V		
		5.5	1.5	2.0	2.0		or V _C	_{CC} – 0.1 V			
V _{IL}	Maximum Low Level Input Voltage	4.5	1.5	0.8	0.8	V	V _{OU} T	_r = 0.1 V			
		5.5	1.5	0.8	0.8		or V ₀	_{CC} – 0.1 V			
V _{OH}	Minimum High Level Output Voltage	4.5	4.49	4.4	4.4	V	I _{OUT}	= -50 μΑ			
		5.5	5.49	5.4	5.4						
						V	*V _{IN}	= V _{IL} or V _{IH}			
		4.5	-	3.86	3.76		I _{OH}	–24 mA			
		5.5	-	4.86	4.76			-24 mA			
V _{OL}	Maximum Low Level Output Voltage	4.5	0.001	0.1	0.1	V	I _{OUT}	= 50 μΑ			
		5.5	0.001	0.1	0.1						
							*V _{IN}	= V _{IL} or V _{IH}			
		4.5	-	0.36	0.44	V	I _{OL}	24 mA			
		5.5	-	0.36	0.44			24 mA			
I _{IN}	Maximum Input Leakage Current	5.5	_	±0.1	±1.0	μΑ	V _I = '	V _{CC} , GND			
ΔI_{CCT}	Additional Max. I _{CC} /Input	5.5	0.6		1.5	mA	V _I = '	V _{CC} – 2.1 V			
l _{OZ}	Maximum 3-State Current	5.5	-	±0.5	±5.0	μΑ	V_{I} (OE) = V_{IL} , V_{IH} V_{I} = V_{CC} , GND V_{O} = V_{CC} , GND				
I _{OLD}	†Minimum Dynamic	5.5	-	-	75	mA	V _{OLE}) = 1.65 V Max			
I _{OHD}	Output Current	5.5	-	-	-75	mA	A V _{OHD} = 3.85 V Min				
I _{CC}	Maximum Quiescent Supply Current	5.5	_	8.0	80	μΑ	V _{IN} =	V _{CC} or GND			

 ^{*} All outputs loaded; thresholds on input associated with output under test.
 † Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS (For Figures and Waveforms – See AND8277/D at www.onsemi.com)

			74ACT			74			
		v _{cc*}	7	$T_A = +25 ^{\circ}\text{C}$ $T_A = -40 ^{\circ}\text{C to } +85 ^{\circ}\text{C}$ $C_L = 50 \text{pF}$			Fig.		
Symbol	Parameter	(V)	Min	Тур	Max	Min	Max	Unit	No.
f _{max}	Maximum Clock Frequency	5.0	100	-	-	85	-	ns	3–3
t _{PLH}	Propagation Delay CP to O _n	5.0	2.5	_	11	2.0	12	ns	3–6
t _{PHL}	Propagation Delay CP to O _n	5.0	2.0	_	10	1.5	11	ns	3–6
t _{PZH}	Output Enable Time	5.0	2.0	-	9.5	1.5	10	ns	3–7
t _{PZL}	Output Enable Time	5.0	2.0	-	9.0	1.5	10	ns	3–8
t _{PHZ}	Output Disable Time	5.0	2.0	-	10.5	1.5	11.5	ns	3–7
t_{PLZ}	Output Disable Time	5.0	2.0	-	8.5	1.5	9.0	ns	3–8

^{*} Voltage Range 5.0 V is 5.0 V ±0.5 V.

AC OPERATING REQUIREMENTS

			74ACT T _A = +25 °C C _L = 50 pF Typ Guarant		74ACT		
		V _{CC} *			$T_A = -40 ^{\circ}\text{C to} +85 ^{\circ}\text{C}$ $C_L = 50 \text{pF}$		Fig.
Symbol	Parameter	(V)			teed Minimum	Unit	No.
t _s	Setup Time, HIGH or LOW D _n to CP	5.0	-	2.5	2.5	ns	3–9
t _h	Hold Time, HIGH or LOW D _n to CP	5.0	-	1.0	1.0	ns	3–9
t _w	CP Pulse Width HIGH or LOW	5.0	-	3.0	4.0	ns	3–6

Voltage Range 3.3 V is 3.3 V ±0.3 V.
 Voltage Range 5.0 V is 5.0 V ±0.5 V.

CAPACITANCE

Symbol	Parameter	Value Typ	Unit	Test Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = 5.0 V
C _{PD}	Power Dissipation Capacitance	40	pF	V _{CC} = 5.0 V

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
MC74AC574DWG	AC574	SOIC-20	38 Units / Rail
MC74AC574DWR2G	AC574	SOIC-20	1000 / Tape & Reel
MC74ACT574DWG	ACT574	SOIC-20	38 Units / Rail
MC74ACT574DWR2G	ACT574	SOIC-20	1000 / Tape & Reel
MC74AC574DTR2G	AC 574	TSSOP-20	2500 / Tape & Reel
MC74ACT574DTR2G	ACT 574	TSSOP-20	2500 / Tape & Reel

[†] For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

REVISION HISTORY

Revision	Description of Changes	Date
10	Modified Output Disable Time for 74AC across temperature range from 4.5 ns to 4.0 ns.	07/02/2025

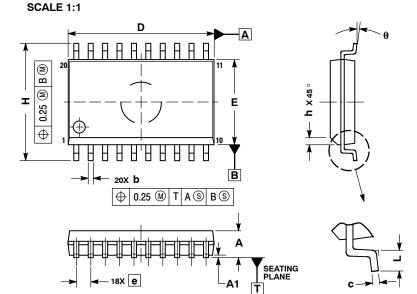
This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.





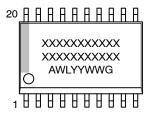
SOIC-20 WB CASE 751D-05 **ISSUE H**

DATE 22 APR 2015



- DIMENSIONS ARE IN MILLIMETERS.
 INTERPRET DIMENSIONS AND TOLERANCES.
- PER ASME Y14.5M, 1994.
 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD
- PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL

	MILLIMETERS		
DIM	MIN	MAX	
Α	2.35	2.65	
A1	0.10	0.25	
b	0.35	0.49	
С	0.23	0.32	
D	12.65	12.95	
E	7.40	7.60	
е	1.27	BSC	
Н	10.05	10.55	
h	0.25	0.75	
L	0.50	0.90	
A	0 °	7 °	



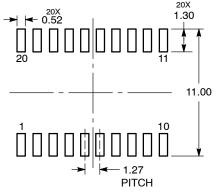
GENERIC MARKING DIAGRAM*

XXXXX = Specific Device Code = Assembly Location

WL = Wafer Lot ΥY = Year WW = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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